Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

Send any inquiries to http://www.renesas.com/inquiry.

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Regarding the change of names mentioned in the document, such as Mitsubishi Electric and Mitsubishi XX, to Renesas Technology Corp.

The semiconductor operations of Hitachi and Mitsubishi Electric were transferred to Renesas Technology Corporation on April 1st 2003. These operations include microcomputer, logic, analog and discrete devices, and memory chips other than DRAMs (flash memory, SRAMs etc.) Accordingly, although Mitsubishi Electric, Mitsubishi Electric Corporation, Mitsubishi Semiconductors, and other Mitsubishi brand names are mentioned in the document, these names have in fact all been changed to Renesas Technology Corp. Thank you for your understanding. Except for our corporate trademark, logo and corporate statement, no changes whatsoever have been made to the contents of the document, and these changes do not constitute any alteration to the contents of the document itself.

Note : Mitsubishi Electric will continue the business operations of high frequency & optical devices and power devices.

Renesas Technology Corp. Customer Support Dept. April 1, 2003

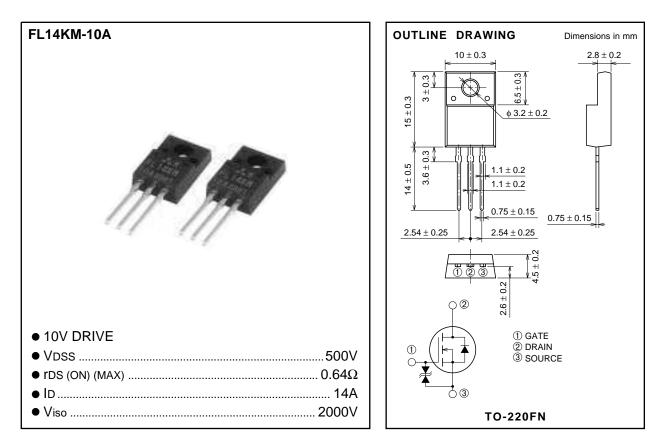


Notice: This is not a final specification Some parametric limits are subject to

MITSUBISHI POWER MOSFET

FL14KM-10A

HIGH-SPEED SWITCHING USE Nch POWER MOSFET



APPLICATION

Inverter type fluorescent light sets, SMPS

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit	
VDSS	Drain-source voltage	VGS = 0V	500	V	
Vgss	Gate-source voltage	VDS = 0V	±30	V	
ID	Drain current		14	A	
IDM	Drain current (Pulsed)		42	A	
IDA	Avalanche current (Pulsed)	L = 200µH	14	A	
PD	Maximum power dissipation		40	W	
Tch	Channel temperature		-55 ~ +150	°C	
Tstg	Storage temperature		-55 ~ +150	°C	
Viso	Isolation voltage AC for 1 minute, Terminal to case		2000	V	
_	Weight	Typical value	2.0	g	



Aug. 1999



FL14KM-10A

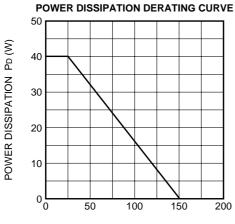
HIGH-SPEED SWITCHING USE Nch POWER MOSFET

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

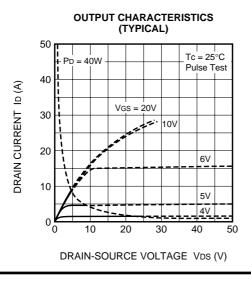
Symbol	Parameter	Test conditions	Limits			11.54
			Min.	Тур.	Max.	Unit
V (BR) DSS	Drain-source breakdown voltage	ID = 1mA, $VGS = 0V$	500	_	_	V
V (BR) GSS	Gate-source breakdown voltage	$IGS = \pm 100 \mu A$, $VDS = 0V$	±30	—	_	V
Igss	Gate-source leakage current	$VGS = \pm 25V, VDS = 0V$	_	_	±10	μA
IDSS	Drain-source leakage current	VDS = 500V, VGS = 0V	—	_	1.0	mA
VGS (th)	Gate-source threshold voltage	ID = 1mA, $VDS = 10V$	2.0	3.0	4.0	V
rds (ON)	Drain-source on-state resistance	ID = 7A, VGS = 10V	_	0.50	0.64	Ω
VDS (ON)	Drain-source on-state voltage	ID = 7A, VGS = 10V	—	3.5	4.5	V
yfs	Forward transfer admittance	ID = 7A, VDS = 10V	_	10.0	_	S
Ciss	Input capacitance	VDS = 25V, VGS = 0V, f = 1MHz	—	1500	—	pF
Coss	Output capacitance		_	180	-	pF
Crss	Reverse transfer capacitance		—	60	—	pF
td (on)	Turn-on delay time	VDD = 200V, ID = 7A, VGS = 10V, RGEN = RGS = 50Ω	_	30	_	ns
tr	Rise time		—	60	—	ns
td (off)	Turn-off delay time		_	250	_	ns
tf	Fall time		_	115	_	ns
Vsd	Source-drain voltage	IS = 7A, VGS = 0V	_	1.5	2.0	V
Rth (ch-c)	Thermal resistance	Channel to case	_	_	3.13	°C/W

Renesas Technology Corp.

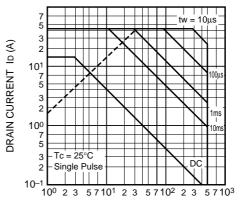
PERFORMANCE CURVES



CASE TEMPERATURE TC (°C)

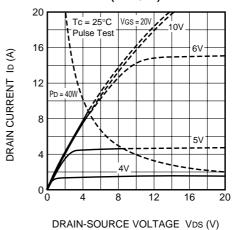


MAXIMUM SAFE OPERATING AREA



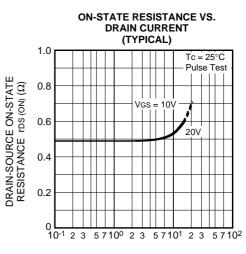
DRAIN-SOURCE VOLTAGE VDs (V)

OUTPUT CHARACTERISTICS (TYPICAL)

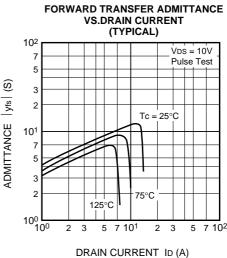


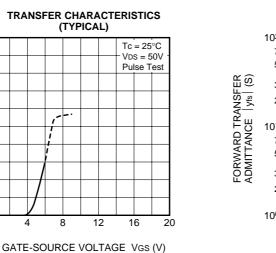
FL14KM-10A

HIGH-SPEED SWITCHING USE Nch POWER MOSFET



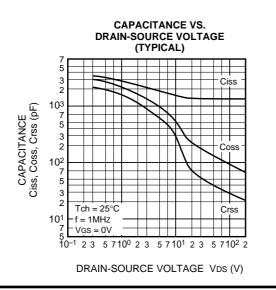
DRAIN CURRENT ID (A)

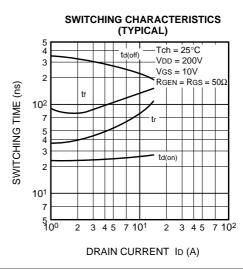


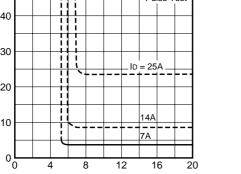


ΕΝΕSΔS

RenesasTechnologyCorp.







 $Tc = 25^{\circ}C$

- Pulse Test

ON-STATE VOLTAGE VS.

GATE-SOURCE VOLTAGE

(TYPICAL)

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GATE-SOURCE VOLTAGE VGs (V)

Notice: This is not a final specification. Some parametric limits are subject to change

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ID (A)

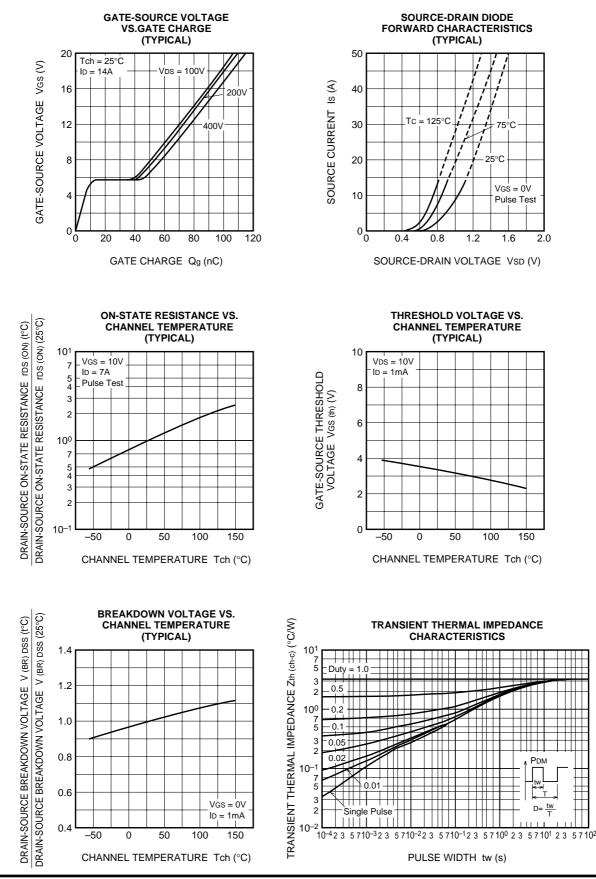
DRAIN CURRENT

DRAIN-SOURCE ON-STATE VOLTAGE VDS (ON) (V)

Aug. 1999

FL14KM-10A

HIGH-SPEED SWITCHING USE Nch POWER MOSFET



Notice: This is not a final specification Some parametric limits are subject to

PREL

